

Supporting Information

Hydrogen and nitrogen codoping of anatase TiO₂ for efficiency enhancement in organic solar cells

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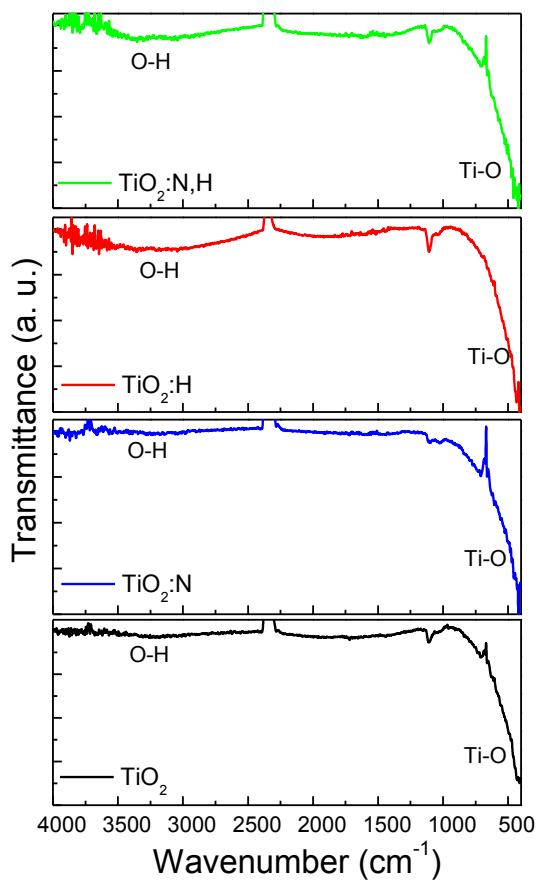


Figure S1. FTIR transmittance spectra of TiO_2 samples either as-deposited (on silicon substrates) or annealed in nitrogen, hydrogen and forming gas (containing 90% nitrogen and 10% hydrogen) at 550 °C for 1 h. The thickness of the samples was ~40 nm.

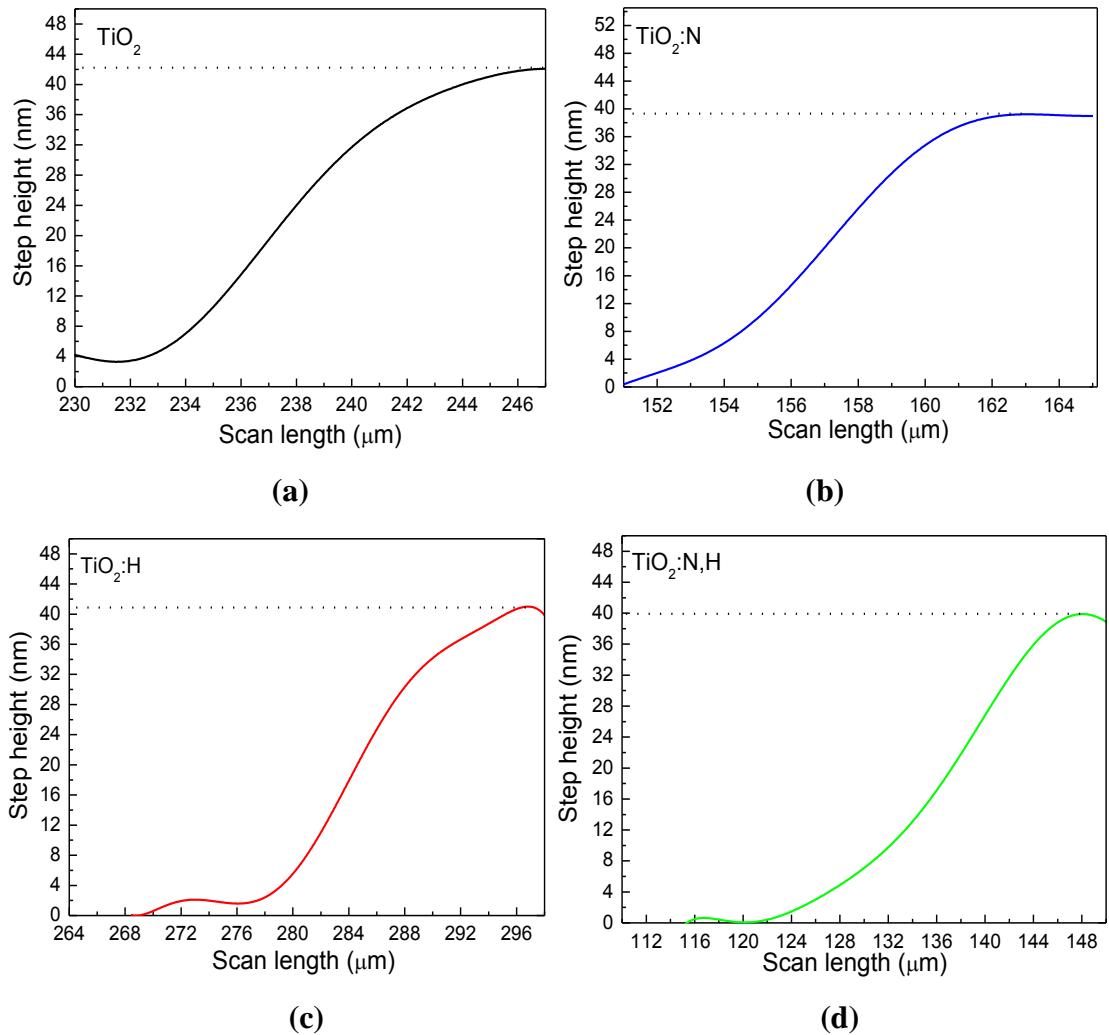


Figure S2. Profilometer thickness profile measurements of TiO_2 samples.

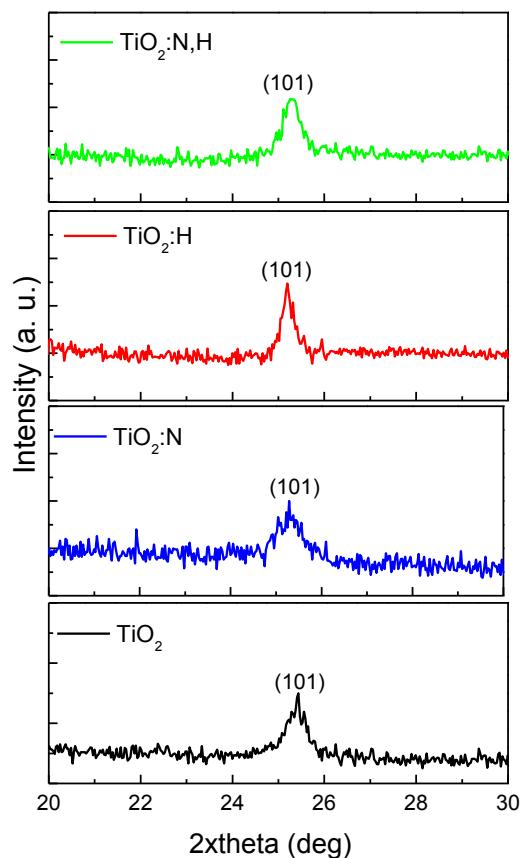


Figure S3. X-ray diffraction patterns of TiO_2 samples with a thickness of ~ 40 nm. The samples were either as-deposited or annealed in nitrogen, hydrogen and forming gas at 550 $^{\circ}\text{C}$ for 1 h.

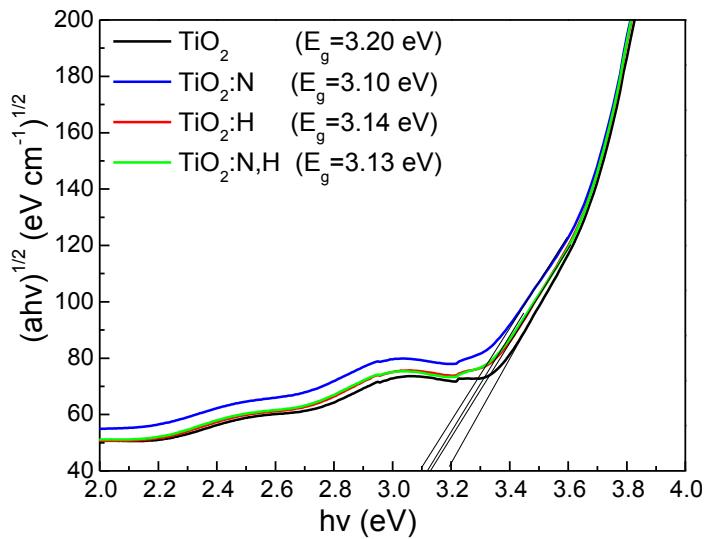


Figure S4. Tauc plots, as derived from absorption measurements, for the estimation of bandgap for the different TiO_2 samples.

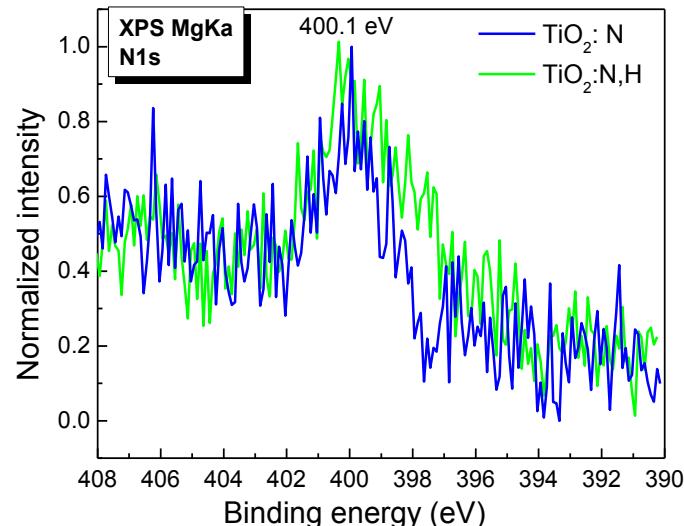


Figure S5. XPS N 1s peaks of TiO_2 samples annealed in nitrogen and forming gas environments at 550°C for 1 hour.

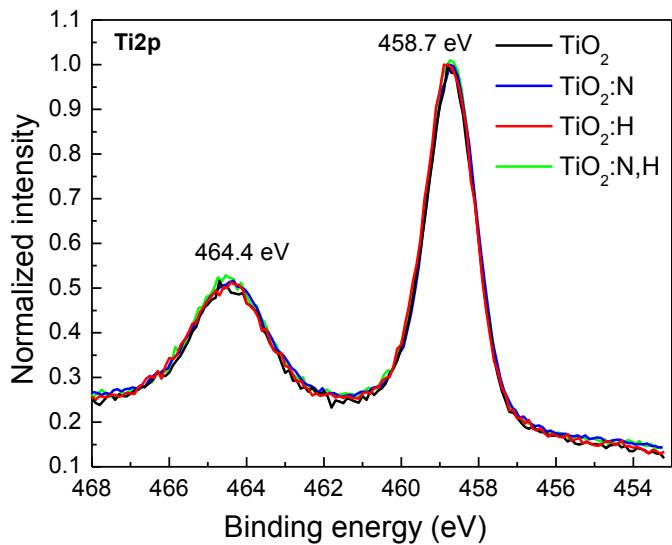


Figure S6. XPS Ti 2p peaks of TiO_2 samples annealed in different environments.

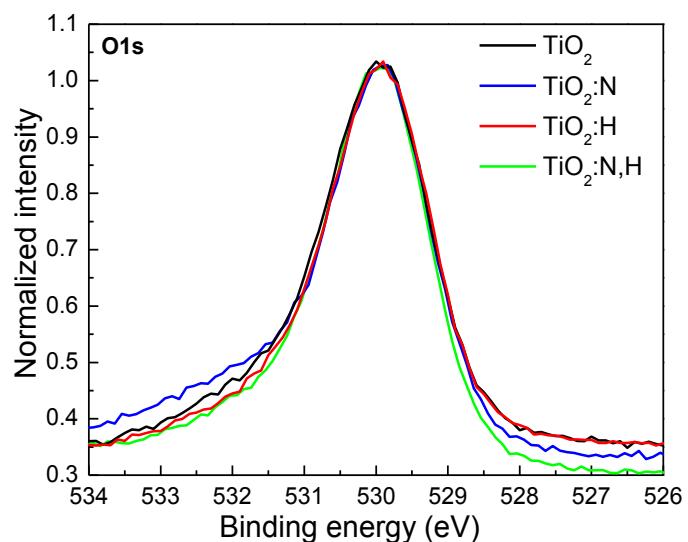


Figure S7. XPS O 1s peaks of TiO_2 samples annealed in different environments.

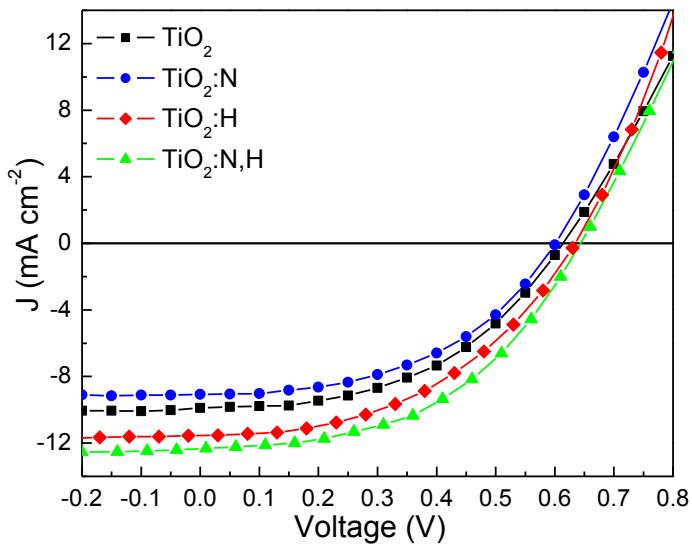


Figure S8. Current density versus applied voltage (J-V) curves taken under 1.5 AM illumination of P3HT:PC₇₀BM-based organic solar cells using N and H doped and codoped TiO₂ ETLs. The annealing in different environments was performed at 550 °C for 1 hour.

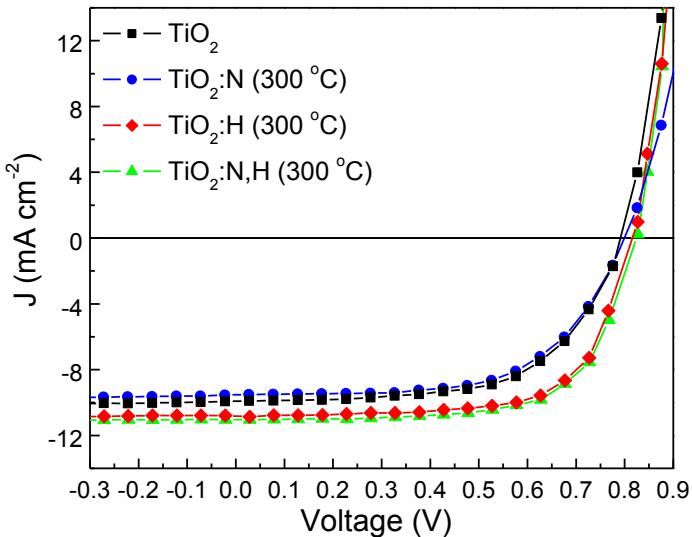


Figure S9. Current density versus applied voltage (J-V) curves taken under 1.5 AM illumination of P3HT:IC₆₀BM-based organic solar cells using TiO₂ ETLs. The TiO₂ layers were either as-deposited or annealed in nitrogen, hydrogen and forming gas at 300 °C for 30 min.